imall

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BB669/BB689...

Silicon Tuning Diode

- For VHF TV tuners
- Very high capacitance ratio
- Low series resistance

2

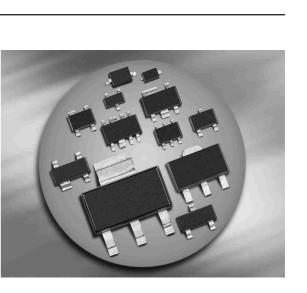
- Excellent uniformity and matching due to "in-line" matching assembly procedure
- Pb-free (RoHS compliant) package



1

BB669 BB689 BB689-02V

K



Туре	Package Configuration		L_S (nH)	Marking
BB669	SOD323	single	1.8	red 1
BB689	SCD80	single	0.6	EE
BB689-02V	SC79	single	0.6	E

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V _R	30	V
Peak reverse voltage	V _{RM}	35	
$(R \leq 5k\Omega)$			
Forward current	I _F	20	mA
Operating temperature range	T _{op}	-55 150	°C
Storage temperature	T _{stg}	-55 150	



Parameter	Symbol		Unit			
			typ.	max.	1	
DC Characteristics						
Reverse current	l _R				nA	
V _R = 30 V		-	-	10		
$V_{\rm R}$ = 30 V, $T_{\rm A}$ = 85 °C		-	-	200		
Electrical Characteristics at $T_A = 25^{\circ}$ C, unless	s otherwise s	pecified				
Parameter	Symbol		Values			
		min.	typ.	max.		
AC Characteristics		_				
Diode capacitance	CT				pF	
$V_{R} = 1 V, f = 1 MHz$		51	56.5	61.5		
$V_{R} = 2 V, f = 1 MHz$		39.6	43.4	47.2		
V _R = 25 V, <i>f</i> = 1 MHz		2.6	2.8	3		
V _R = 28 V, <i>f</i> = 1 MHz		2.5	2.7	2.9		
Capacitance ratio	C _{T1} /C _{T28}	18	20.9	23.2	-	
$V_{\rm R}$ = 1 V, $V_{\rm R}$ = 28 V, f = 1 MHz						
Capacitance ratio	C _{T2} /C _{T25}	14.5	15.5	17	1	
V _R = 2 V, V _R = 25 V, <i>f</i> = 1 MHz						
Capacitance matching ¹⁾	$\Delta C_{T}/C_{T}$	-	-	2	%	
$V_{\rm R}$ = 1 28 V, f = 1 MHz, 7 diodes sequence						
Series resistance	r _S	-	0.85	1.2	Ω	
V _R = 8 V, <i>f</i> = 470 MHz						
Series inductance	LS	_	0.6	-	nH	

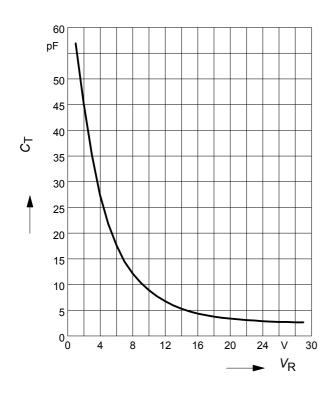
Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

¹For details please refer to Application Note 047



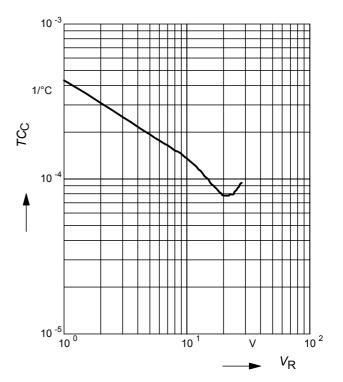
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz



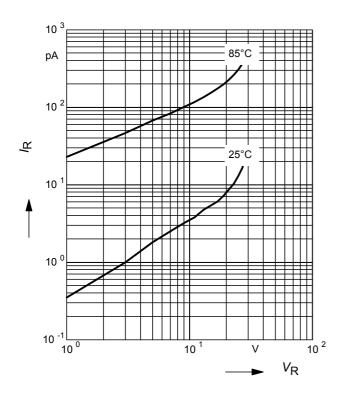
Temperature coefficient of the diode

capacitance $T_{Cc} = f(V_R)$

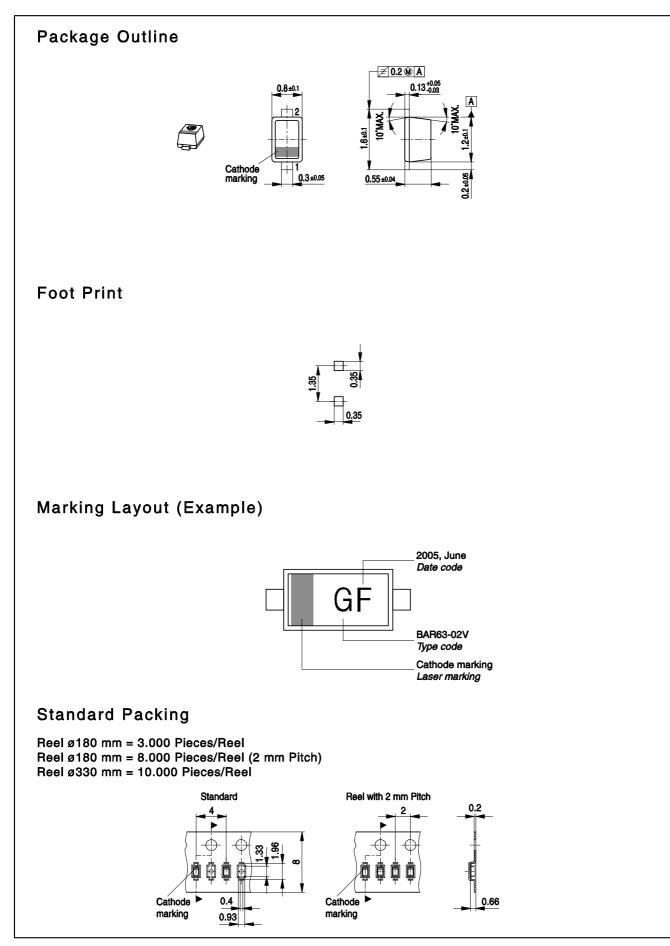


Reverse current $I_{R} = f(V_{R})$

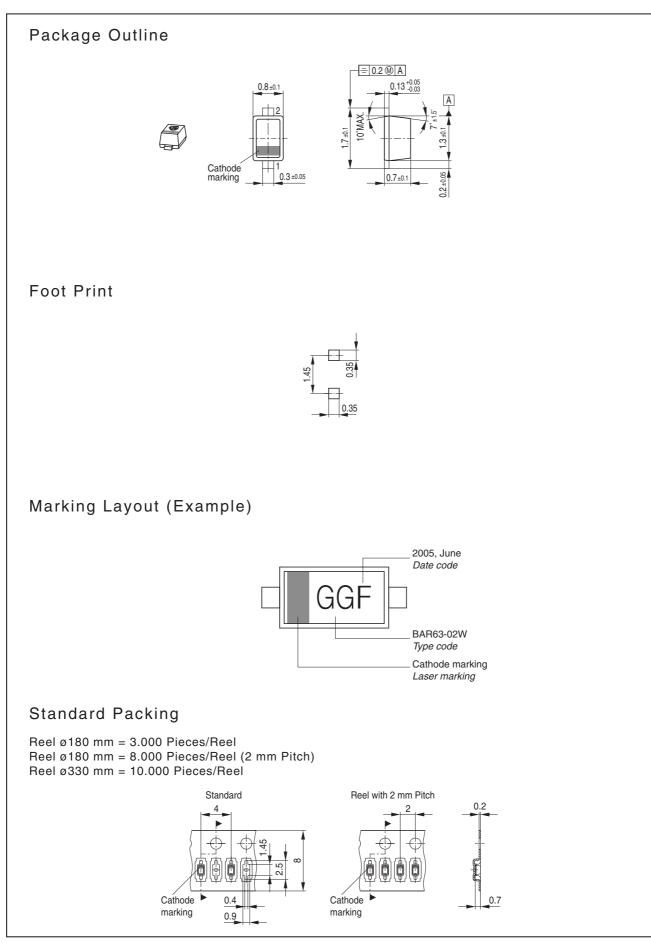
 T_A = Parameter













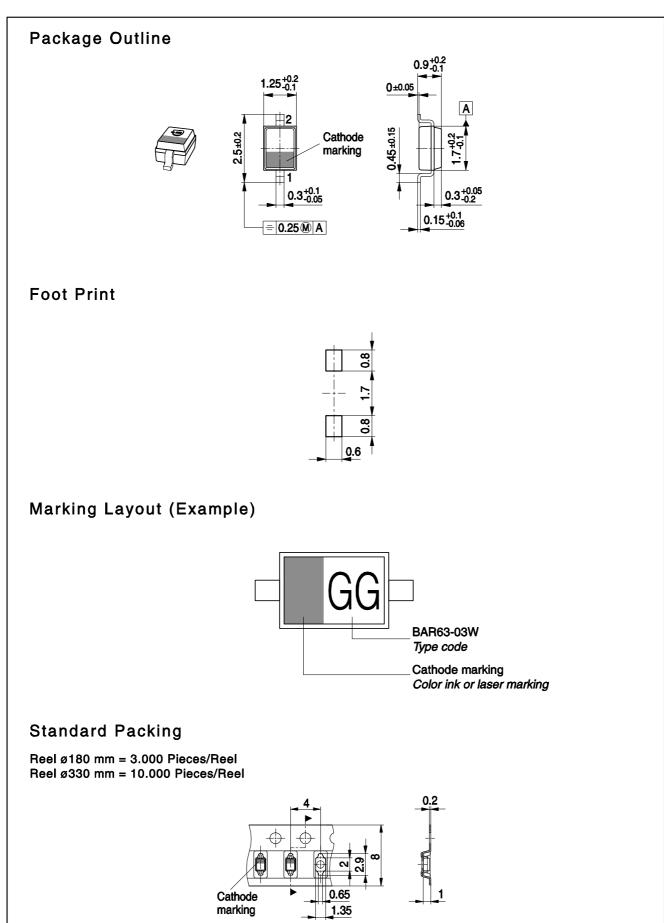
Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	А	Р	а	р	А	Р	а	р	А	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	S	D	S
05	е	t	E	Т	е	t	E	Т	е	t	E	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	V	G	V	g	V	G	V	g	V	G	V
08	h	х	Н	Х	h	Х	Н	Х	h	Х	Н	Х
09	j	у	J	Y	j	у	J	Y	j	у	J	Y
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	I	2	L	4	I	2	L	4
12	n	3	Ν	5	n	3	Ν	5	n	3	Ν	5

1) New Marking Layout for SC75, implemented at October 2005.

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